

30% Triple-Junction (TJ) III-V Bare Solar Cells & Assemblies

TJ 3G30-Advanced (HP)

Providing best cost-performance ratio in space applications



Product Identifiers	Bare Cell	Assembly (SCA / CIC)
AZUR SPACE Material (Part) Number	82645	82643
AZUR SPACE Drawing Number	ZP-00010472	ZP-00010473

AZUR SPACE's 3G30-Advanced bare solar cells and solar cell assemblies ("SCA"), or CICs (Cell-interconnect-coverglass) are the ideal solution for space power applications in conventional or in New Space segments. The award-winning 3G30-Advanced technology design offers proven best-in-class end-of-life (EOL) performance at lowest Cost-per-Watt, enabling a multitude of heritage options for all orbits and missions.

The 3G30C-Advanced bare cell device is a space-qualified InGaP/GaAs/Ge triple-junction solar cell originating from a 150 mm germanium (Ge) substrate and provides 30% class beginning-of-life (BOL) efficiency. This device includes AZUR SPACE's proprietary radiation-hardened design for best EOL performance. Our standard cell features well-proven metallization as well as an improved busbar and grid-design with two contact pads plus one for a discrete bypass diode connection and a standard bare cell size of 77.55 cm² (6 cm x 14 cm, multiple crops per corner, or "half-pipe"). This configuration offers an unthinned bare cell total thickness of 245 µm. The 3G30C solar cell is compatible with an external bypass diode, which is also available from AZUR SPACE together with bare cell orders.

The 3G30A assembly includes a bare 3G30C-Advanced solar cell, a corner-mounted silicon bypass diode, welded in-plane silver-coated Kovar interconnectors ("ICs"), and a 100 µm AR coated coverglass bonded with space-grade heritage adhesive. This assembly has a standard size of 78.64 cm² (glass size) and has an assembly total device thickness of 380 µm. A digital CAD / CAM STEP file as well as digital device photographs of bare cell or assembly devices are available upon request.

Other non-standard sizes, thicknesses and configurations are also available upon request. Thickness and mass values and variations of the above standard devices are shown below.

The 3G30-Advanced technology, cells and assemblies are ECSS-E-ST-20-08C (Rev. 1) qualified. These devices are all produced in our mature MRL-10 Heilbronn facility. Our technology and products have demonstrated in-orbit TRL-9 level heritage. AZUR SPACE is certified to ISO 9001:2015 (QMS), EN 9100:2018 (QMS, European equivalent to AS 9100D), as well as ISO 14001:2015 (Environmental) and ISO 45001:2018 (Health & Safety).

30% Triple-Junction Solar Cells & Assemblies

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Design and Mechanical Data		3G30C-Adv. Bare Cell	3G30A-Adv. Assembly (SCA / CIC)
AZUR SPACE Material (Part) Number		82645	82643
Base Material		InGaP/GaAs/Ge on Ge	InGaP/GaAs/Ge on Ge
AR-Coating		TiO ₂ /Al ₂ O ₃	TiO ₂ /Al ₂ O ₃
Outer Dimensions (mm)		145.90 (± 0.1) x 60.69 (± 0.1)	146.10 (± 0.1) x 60.89 (± 0.1)
Cell Area (cm ²)		77.55	78.64 glassed area (cell area is 77.55)
Average Weight		≤ 134 mg/cm ² / 10.4 grams	≤ 170 mg/cm ² / 13.1 grams
Thickness (μm)		245 (± 25)	380 (± 50)
Coverglass		n/a	100 μm AR coated
Contacts		2x front side pads (plus diode pad)	2x Interconnects
Interconnector Configuration		n/a	In-Plane
Interconnector Material		n/a	Silver (Ag) coated Kovar
Interconnector Dimensions		n/a	8.1 mm x 13.0 mm x 25 μm

Typical Electrical Performance	BOL		5E13		2.5E14		5E14		1E15		1E16	
	Cell	CIC	Cell	CIC	Cell	CIC	Cell	CIC	Cell	CIC	Cell	CIC
V _{oc}	[mV]	2700	2700	2633	2633	2584	2584	2552	2552	2519	2519	2341
I _{sc}	[mA]	1317	1303	1312	1298	1309	1295	1306	1293	1268	1255	1008
V _{mp}	[mV]	2395	2395	2321	2321	2282	2282	2247	2247	2215	2215	2112
I _{mp}	[mA]	1284	1269	1276	1261	1274	1259	1270	1255	1234	1220	917
η (1367 W/m ²)	[%]	29.0	28.7	27.9	27.6	27.4	27.1	26.9	26.6	25.8	25.5	18.3
η (1353 W/m ²)	[%]	29.3	29.0	28.2	27.9	27.7	27.4	27.2	26.9	26.1	25.7	18.5

QTR 3558-00-01, QTR 4151-01-01, QTR 4761-01-01. Standard: CASOLBA 2005 (05-20MV1, etc.); Spectrum: AM0 WRC, 1367 W/m²; T = 28°C, fluence 1 MeV e- [e/cm²]. Other fluences and proton degradation data available on request. Radiation hardness is periodically assessed.

Typical Temperature Coefficients	BOL		2.5E14		5E14		1E15	
	Cell or CIC							
ΔV _{oc} /ΔT	[mV/°C]	-6.2	-6.5	-6.6	-6.7			
ΔI _{sc} /ΔT	[mA/°C]	0.93	0.85	0.91	0.99			
ΔV _{mp} /ΔT	[mV/°C]	-6.7	-6.8	-7.1	-7.2			
ΔI _{mp} /ΔT	[mA/°C]	0.62	0.51	0.62	0.72			

QTR 3558-00-01, QTR 4151-01-01, QTR 4761-01-01; Temperature range 28°C – 140°C; fluence 1 MeV e- [e/cm²]

Other Information	Item	Typical Value
Diode (Assemblies)	External Si Protection Diode	V _{forward} (620 mA) ≤ 0.8 V (T = 25°C ± 3°C) I _{reverse} (4 V) ≤ 0.1 μA
Threshold Absorptivity	Absorptivity Value	≤ 0.91 (100 μm AR coverglass)
Threshold Pull Test	Pull Test Values	> 1.6 N at 45° (with 12.5 μm Ag strips) > 7.0 N at 0° (with standard Kovar interconnectors)

These performance data reflect a defined configuration at a specific mission environment across a large manufacturing population. Changes in configuration or production order volume may modify typical performance values.

Please refer to the AZUR SPACE **General Information Sheet** for additional information including in-orbit heritage, quality certifications, business licenses, product registrations and general company information at www.azurspace.com. Contact information is shown below and is also available on our website.



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